



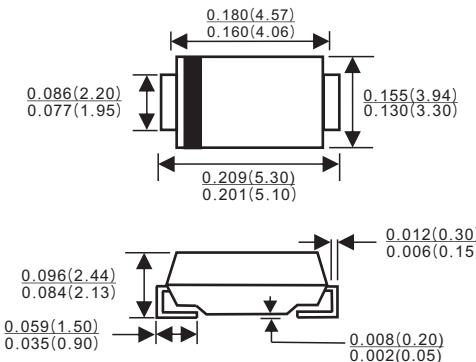
REVERSE VOLTAGE: 20 --- 100 V
CURRENT: 5.0 A



Features

- ◊ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◊ For surface mounted applications
- ◊ Low profile package
- ◊ Built-in strain relief
- ◊ Metal silicon junction, majority carrier conduction
- ◊ High surge capability
- ◊ High current capability, low forward voltage drop
- ◊ Low power loss, high efficiency
- ◊ For use in low voltage high frequency inverters, free wheeling and polarity protection applications
- ◊ Guardring for overvoltage protection
- ◊ High temperature soldering guaranteed: 250°C/10 seconds at terminals

SMB/DO-214AA



Dimensions in inches and (millimeters)

Mechanical Data

- ◊ Case: JEDEC SMB, molded plastic over passivated chip
- ◊ Polarity: Color band denotes cathode end
- ◊ Weight: 0.093 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

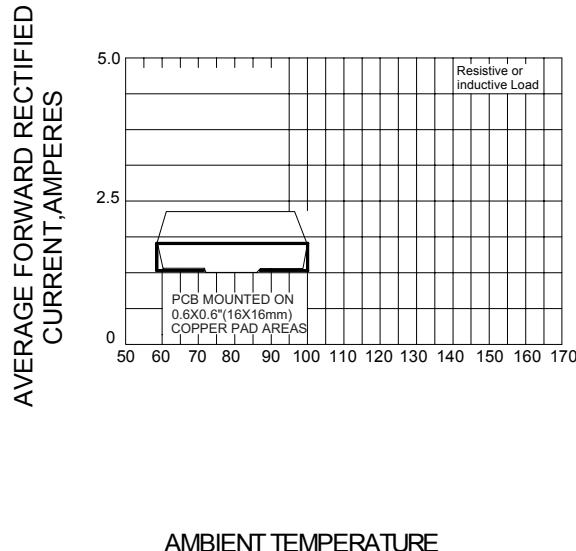
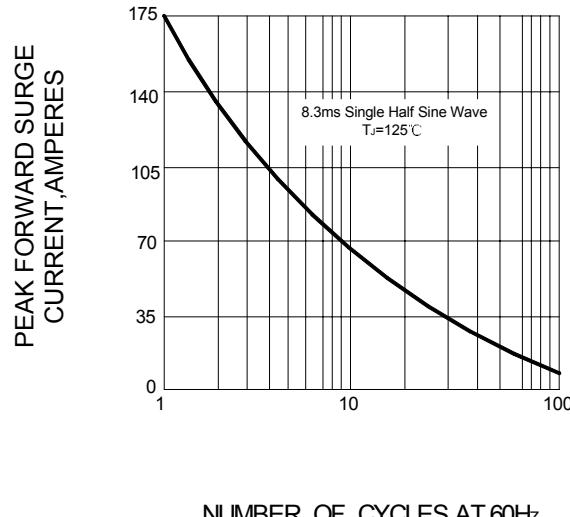
Ratings at 25°C ambient temperature unless otherwise specified

		SS52L	SS53L	SS54L	SS55L	SS56L	SS58L	SS59L	SS510L	UNITS			
Maximum recurrent peak reverse voltage	V _{RRM}	20	30	40	50	60	80	90	100	V			
Maximum RMS voltage	V _{RWS}	14	21	28	35	42	56	63	70	V			
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	90	100	V			
Maximum average forward rectified current at T _L (SEE FIG.1) (NOTE 2)	I _(AV)	5.0							A				
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	175							A				
Maximum instantaneous forward voltage at 5.0A(NOTE 1)	V _F	0.45		0.52		0.72							
Maximum DC reverse current @T _A =25°C at rated DC blocking voltage(NOTE1) @T _A =100°C	I _R	0.5				20				mA			
Typical thermal resistance (NOTE2)	R _{JA} R _{JL}	55				17							
Operating junction temperature range	T _J	-55---+150							°C				
Storage temperature range	T _{STG}	-55---+150							°C				

NOTE: 1. Pulse test: 300 μS pulse width, 1% duty cycle

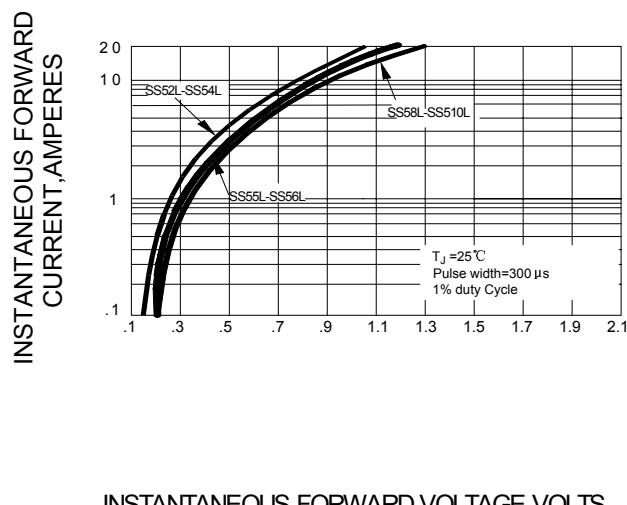
2. P.C.B. mounted with 0.55"X0.55"(14.0X14.0mm²) copper pad areas

Ratings AND Characteristic Curves

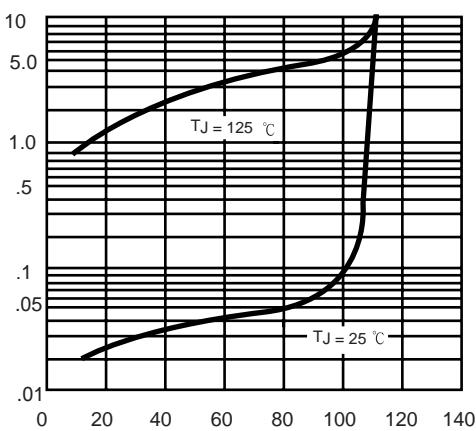
FIG.1 – FORWARD DERATING CURVE**FIG.2 – PEAK FORWARD SURGE CURRENT**

AMBIENT TEMPERATURE

NUMBER OF CYCLES AT 60Hz

FIG.3 – TYPICAL FORWARD CHARACTERISTICS

INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4 – TYPICAL REVERSE CHARACTERISTICS

PERCENT OF RATED PEAK REVERSE VOLTAGE, %

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by LGE manufacturer:

Other Similar products are found below :

[CUS06\(TE85L,Q,M\)](#) [MA4E2039](#) [D1FH3-5063](#) [MBR0530L-TP](#) [MBR10100CT-BP](#) [MBR30H100MFST1G](#) [MMBD301M3T5G](#) [PMAD1103-LF](#) [PMAD1108-LF](#) [RB160M-50TR](#) [RB520S-30](#) [RB551V-30](#) [DD350N18K](#) [DZ435N40K](#) [DZ600N16K](#) [BAS16E6433HTMA1](#) [BAS 3010S-02LRH E6327](#) [BAT 54-02LRH E6327](#) [IDL02G65C5XUMA1](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#) [SBAT54CWT1G](#) [SBM30-03-TR-E](#) [SBS818-TL-E](#) [SK32A-LTP](#) [SK33A-TP](#) [SK34A-TP](#) [SK34B-TP](#) [SMD1200PL-TP](#) [ACDBN160-HF](#) [SS3003CH-TL-E](#) [STPS30S45CW](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#) [MBR1240MFST1G](#) [MBRB30H30CT-1G](#) [BAS28E6433HTMA1](#) [BAS 70-02L E6327](#) [HSB123JTR-E](#) [JANTX1N5712-1](#) [VS-STPS40L45CW-N3](#) [DD350N12K](#) [SB007-03C-TB-E](#) [SB10015M-TL-E](#) [SB1003M3-TL-E](#) [SK110-LTP](#)